

### ITAxxB3

### Bidirectional Transil™ array for data line protection

#### **Features**

- High surge capability Transil array: I<sub>PP</sub> = 40 A (8/20 µs)
- Peak pulse power: 300 W (8/20 µs)
- Separated Input Output
- Up to 9 bidirectional Transil functions
- Low clamping factor (V<sub>CL</sub>/V<sub>BR</sub>) at high current level
- Low leakage current
- ESD protection up to 15 kV

#### Complies with the following standards

- IEC 61000-4-2 level 4
  - 15 kV (air discharge)
  - 8 kV (contact discharge)
- MIL STD 883G- Method 3015-7: class 3B
  - 25 kV (human body model)

### **Applications**

Differential data transmission lines protection, such as :

- RS-232
- RS-423
- RS-422
- RS-485



#### **Description**

Transil diode arrays provide high overvoltage protection by clamping action. Their instantaneous response to transient overvoltages makes them particularly suited to protect voltage sensitive devices such as MOS technology and low voltage supplied IC's.

The ITA series combines high surge capability against energetic pulses with high voltage performance against ESD.

The separated input/output configuration of the device ensures improved protection against very fast transient overvoltage like ESD by elimination of the spikes induced by parasitic inductances created by external wiring.

GND 1 20 GND
INPUT 2 19 OUTPUT
INPUT 3 18 OUTPUT
INPUT 5 16 OUTPUT
INPUT 6 15 OUTPUT
INPUT 7 14 OUTPUT
INPUT 8 13 OUTPUT
INPUT 9 12 OUTPUT
GND 10 11 GND

Figure 1. Functional diagram

TM: Transil is a trademark of STMicroelectronics

November 2007 Rev 2 1/8

Characteristics ITAxxB3

## 1 Characteristics

Table 1. Absolute ratings  $(T_{amb} = 25 \,^{\circ}C)$ 

	3- Callib /			
Symbol	Parameter	Value	Unit	
P <sub>PP</sub>	Peak pulse power (8/20 μs) <sup>(1)</sup>	300	W	
I <sub>PP</sub>	Peak pulse current (8/20 µs) <sup>(1)</sup>	40	Α	
I <sup>2</sup> t	Wire I <sup>2</sup> t value <sup>(1)</sup>	0.6	A <sup>2</sup> s	
Tj	Maximum operating junction temperature	125	°C	
T <sub>stg</sub>	Storage temperature range	-55 to +150	°C	
TL	Maximum lead temperature for soldering during 10 s	260	°C	

<sup>1.</sup> For surges greater than the specified maximum value, the I/O will first present a short-circuit and after an open circuit caused by the wire melting.

Table 2. Electrical characteristics  $(T_{amb} = 25 \, ^{\circ}C)$ 

IUDIC Z.		oti ioai t	ilai acto	113003 (1	amb	<del>5 0,</del>					
Symbol			Paramete	er							
$V_{RM}$	Stan	Stand-off voltage						<u> </u>		IPP	
V <sub>BR</sub>	Brea	Breakdown voltage									
V <sub>CL</sub>	Clan	nping volt	age								
I <sub>RM</sub>	Leakage current							IRM	VRM	V <sub>CL</sub> V	
I <sub>PP</sub>	Peal	k pulse cu	ırrent						Vi	BR	
αΤ	Volta	age tempe	erature co	efficient							
V <sub>F</sub>	Forward voltage drop						1				
С	Capacitance										
		$V_{BR}$	@ I <sub>R</sub>	I <sub>RM</sub> @	V <sub>RM</sub>	V <sub>CL</sub>	@ I <sub>PP</sub>	V <sub>CL</sub>	@ I <sub>PP</sub>	αΤ	С
Order co	مام	min.		max.			8/20 µs	max.	8/20 µs	max.	max.
Order Co	ue	(1)				(1)		(1)			(2)
		V	mA	μA	V	٧	Α	V	Α	10 <sup>-4</sup> /°C	pF
ITA6V5E	33	6.5	1	10	5	9.5	10	121	25	4	1100
ITA18B	3	18	1	4	15	21	10	26	25	9	500
ITA25B	3	25	1	4	24	31	10	36	25	12	420

<sup>1.</sup> Between I/O pin and ground.

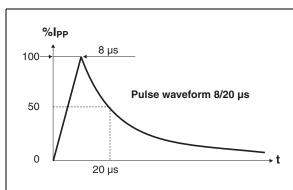
**577** 

<sup>2.</sup> Between two input pins at 0 V Bias, F = 1 MHz.

ITAxxB3 Characteristics

Figure 2. Pulse waveform

Figure 3. Typical peak pulse power versus exponential pulse duration



Ppp(W)

1E+04

1E+03

1E+03

1E+01

1E-03

1E-02

1E+01

1E+01

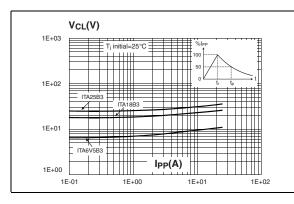
1E+01

1E+01

1E+02

Figure 4. Clamping voltage versus peak pulse current (exponential waveform 8/20 µs)

Figure 5. Peak current I<sub>DC</sub> inducing open circuit of the wire for one input/output versus pulse duration (typical values)



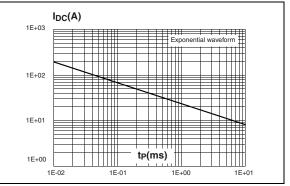
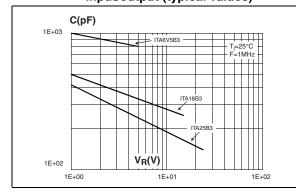
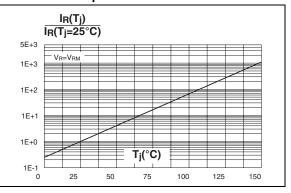


Figure 6. Junction capacitance versus reverse applied voltage for one input/output (typical values)

Figure 7. Relative variation of leakage current versus junction temperature





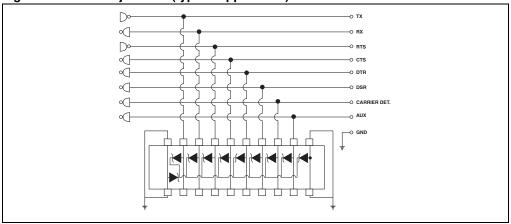
# 2 Application information

This monolithic Transil Array is based on 610 unidirectional Transils with a common cathode and can be configurated to offer up to 9 bidirectional functions. This imposes a maximum differential voltage between 2 input pins (see *Table 3*).

Table 3. Maximum differential voltages

Order code	Maximum differential voltage between two input pins at 25°C
ITA6V5B3	± 3.5 v
ITA18B3	± 9.0 v
ITA25B3	± 12.5 v

Figure 8. RS-232 junction (typical application)



# 2.1 Design advantage of ITAxxB3 used with 4-point structure

The ITAxxxB3 has been designed with a 4-point structure **Figure 9**. **The 4 point structure** 

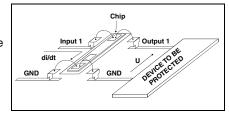
(separated Input/output) to efficiently protect against disturbances with very high di/dt rates, such as ESD. The purpose of this 4-point structure is to eliminate the

The purpose of this 4-point structure is to eliminate the overvoltage introduced by the parasitic inductances of the wiring (Ldi/dt).

Efficient protection depends not only on the component itself, but also on the circuit layout. The drawing given in figure 9 shows the layout to be used in order to take advantage of the 4-point structure of the ITAxxxB3.

With this layout, each line to be protected passes through the protection device.

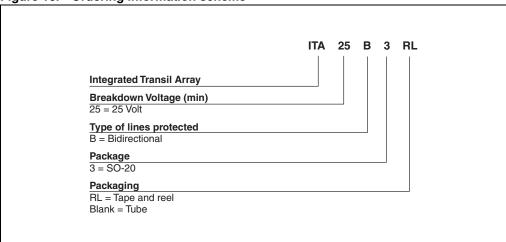
In this way, it realizes an interface between the data line and the circuit to be protected, guaranteeing an isolation between its inputs and outputs.



57

# 3 Ordering information scheme

Figure 10. Ordering information scheme



**577** 

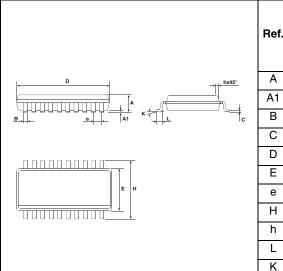
Package information ITAxxB3

## 4 Package information

#### Epoxy meets UL94, V0

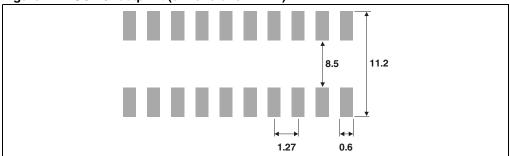
In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 4. SO-20 dimensions



	Dimensions						
Ref.	Mi	illimete	ers	Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	2.35		2.65	0.092		0.104	
A1	0.10		0.30	0.004		0.008	
В	0.33		0.51	0.013		0.020	
С	0.23		0.32	0.009		0.013	
D	12.6		13.0	0.484		0.512	
Е	7.40		7.60	0.291		0.299	
е		1.27			0.050		
Н	10.0		10.65	0.394		0.419	
h	0.25		0.75	0.010		0.029	
L	0.40		1.27	0.016		0.050	
K	8° (max)						

Figure 11. SO-20 footprint (dimensions in mm)



6/8

# 5 Ordering Information

Table 5. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
ITA6V5B3	ITA6V5B3			1000	Tube
ITA18B3	ITA18B3			1000	Tube
ITA18B3RL	ITA18B3	SO-20	0.55 g	1000	Tape and reel
ITA25B3	ITA25B3			1000	Tube
ITA25B3RL	ITA25B3			1000	Tape and reel

# 6 Revision history

Table 6. Document revision history

Date	Revision	Changes
13-Dec-2004	1	Initial release.
07-Nov-2007	2	Reformatted to current standards. Updated leakage current values in <i>Table 2</i> Updated pulse waveform parameters in <i>Figure 2</i> .

#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

**577** 

8/8